



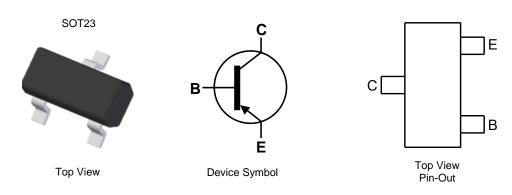
60V PNP MEDIUM POWER TRANSISTOR IN SOT23

Features

- Epitaxial Planar Die Construction
- Ideal for Low Power Amplification and Switching
- Complementary NPN Type: DIODES™ MMBTA05Q / DIODES™ MMBTA06Q
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- The DIODES™ MMBTA55Q and DIODES™ MMBTA56Q are suitable for automotive applications requiring specific change control; these parts are AEC-Q101 qualified, PPAP capable, and manufactured in IATF16949 certified facilities. https://www.diodes.com/quality/product-definitions/

Mechanical Data

- Package: SOT23
- Package Material: Molded Plastic, "Green" Molding Compound;
 UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish-Matte Tin Plated Leads.
 Solderable per MIL-STD-202, Method 208 @3
- Weight: 0.008 grams (Approximate)



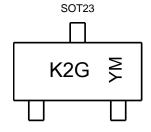
Ordering Information (Note 4)

Part Number	Package	Marking	Reel size (inches)	Tape width (mm)	Packing	
Part Number	Fackage	war King	Reel Size (Illulies)	rape width (min)	Qty.	Carrier
MMBTA55Q-13-F	SOT23	K2G	13	8	10,000	Reel
MMBTA56Q-7-F	SOT23	K2G	7	8	3,000	Reel
MMBTA56Q-13-F	SOT23	K2G	13	8	10,000	Reel

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information



K2G = Product Type Marking Code YM = Date Code Marking Y = Year (ex: J = 2022) M = Month (ex: 9 = September)

Date Code Key

Year	2022	2023	2024	2025	2026	2027	2028	2029	2030	2031	2032	2033
Code	J	K	L	М	N	0	Р	R	S	T	U	V
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec



Absolute Maximum Ratings (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	MMBTA55Q	MMBTA56Q	Unit
Collector-Base Voltage	V_{CBO}	-60	-80	V
Collector-Emitter Voltage	V _{CEO}	-60	-80	V
Emitter-Base Voltage	V _{EBO}	-4	.0	V
Collector Current - Continuous	Ic	-5	00	mA

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
Power Dissipation	(Note 5)	D-	310	mW	
Power Dissipation	(Note 6)	P _D	350	IIIVV	
Thermal Resistance, Junction to Ambient	(Note 5)	D	403	°C/W	
Thermal Resistance, Junction to Ambient	(Note 6)	R _{0JA}	357	C/VV	
Thermal Resistance, Junction to Leads	(Note 7)	$R_{ heta JL}$	350	°C/W	
Operating and Storage Temperature Range		$T_{J,}T_{STG}$	-55 to +150	°C	

ESD Ratings (Note 8)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

Notes:

- 5. For a device mounted on minimum recommended pad layout 1oz copper that is on a single-sided FR4 PCB; device is measured under still air conditions whilst operating in a steady-state.
 6. Same as Note 5, except the device is mounted on 15 mm x 15mm 1oz copper.
- 7. Thermal resistance from junction to solder-point (at the end of the leads).
- 8. Refer to JEDEC specification JESD22-A114 and JESD22-A115.



Thermal Characteristics and Derating Information

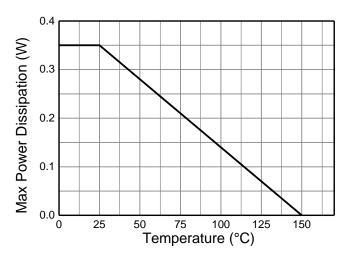


Figure 1. Derating Curve

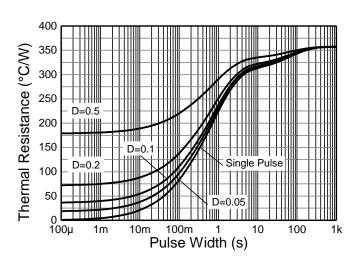


Figure 2. Transient Thermal Impedance

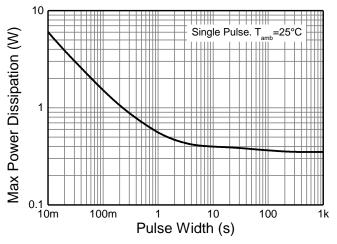


Figure 3. Pulse Power Dissipation



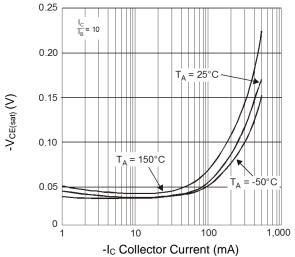
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

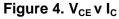
Characteristic			Min	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 9)						
Collector-Base Breakdown Voltage	MMBTA55Q MMBTA56Q	BV _{CBO}	-60 -80	_	V	$I_C = -100\mu A, I_E = 0$
Collector-Emitter Breakdown Voltage	MMBTA55Q MMBTA56Q	BV _{CEO}	-60 -80	_	V	$I_C = -1.0 \text{mA}, I_B = 0$
Emitter-Base Breakdown Voltage		BV _{EBO}	-5.0	-4.0	_	$I_E = -100\mu A, I_C = 0$
Collector Cut-Off Current	MMBTA55Q MMBTA56Q	I _{CBO}	_	-100	nA	$V_{CB} = -60V, I_{E} = 0$ $V_{CB} = -80V, I_{E} = 0$
Collector Cut-Off Current MMBTA55Q MMBTA56Q		ICEX	_	-100	nA	$V_{CE} = -60V, I_{BO} = 0V$ $V_{CE} = -80V, I_{BO} = 0V$
ON CHARACTERISTICS (Note 9)						
DC Current Gain	h _{FE}	100	_	_	I _C = -10mA, V _{CE} = -1.0V I _C = -100mA, V _{CE} = -1.0V	
Collector-Emitter Saturation Voltage	V _{CE(sat)}	_	-0.25	V	$I_C = -100 \text{mA}, I_B = -10 \text{mA}$	
Base-Emitter Saturation Voltage	V _{BE(sat)}	_	-1.2	V	I _C = -100mA, V _{CE} = -1.0V	
SMALL SIGNAL CHARACTERISTICS						
Current Gain-Bandwidth Product		f _T	50	_	MHz	$V_{CE} = -1.0V, I_{C} = -100mA,$ f = 100MHz

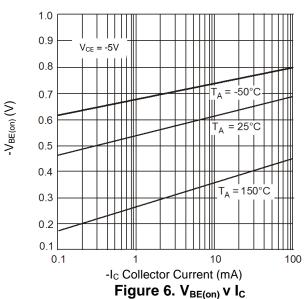
Note: 9. Measured under pulsed conditions. Pulse width $\leq 300 \mu s$. Duty cycle $\leq 2\%$.



Typical Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)







1,000
V_{CE} = -5V

T_A = 150°C

T_A = 25°C

T_A = -50°C

-I_C Collector Current (mA)

Figure 5. h_{FE} v I_C

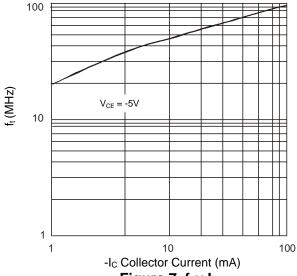


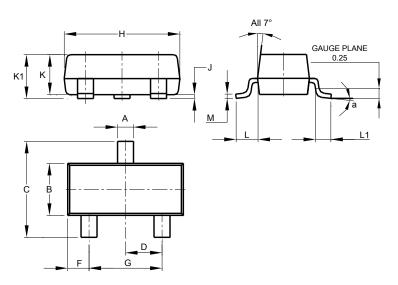
Figure 7. f_t v I_C



Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT23

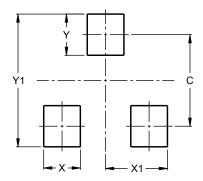


SOT23						
Dim	Min	Max	Тур			
Α	0.37	0.51	0.40			
В	1.20	1.40	1.30			
С	2.30	2.50	2.40			
D	0.89	1.03	0.915			
F	0.45	0.60	0.535			
G	1.78	2.05	1.83			
H	2.80	3.00	2.90			
J	0.013	0.10	0.05			
K	0.890	1.00	0.975			
K 1	0.903	1.10	1.025			
L	0.45	0.61	0.55			
L1	0.25	0.55	0.40			
М	0.085	0.150	0.110			
а	0°	8°				
All	Dimens	ions in	mm			

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT23



Dimensions	Value (in mm)
С	2.0
Х	0.8
X1	1.35
Y	0.9
Y1	2.9



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